

# SILICON POWER TRANSISTOR 2SD2165

# NPN SILICON EPITAXIAL TRANSISTOR FOR LOW-FREQUENCY POWER AMPLIFIERS AND LOW-SPEED SWITCHING

The 2SD2165 is a single power transistor developed especially for high hee. This transistor is ideal for simplifying drive circuits and reducing power dissipation because its hee is as high as that of Darlington transistors, but it is a single transistor.

In addition, this transistor features a small resin-molded insulation package, thus contributing to high-density mounting and mounting cost reduction.

### **FEATURES**

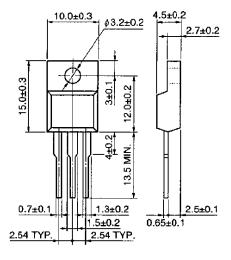
- High hre and low Vce(sat): hre  $\cong$  1,300 TYP. (Vce = 5.0 V, Ic = 1.0 A) Vce(sat)  $\cong$  0.3 V TYP. (Ic = 3.0 A, Ib = 30 mA)
- Mold package that does not require an insulating board or insulation bushing

# ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	Vcво	100	V
Collector to emitter voltage	VCEO	100	V
Emitter to base voltage	V <sub>EBO</sub>	7.0	V
Collector current (DC)	Ic(DC)	6.0	Α
Collector current (pulse)	C(pulse)	10 <sup>Note</sup>	Α
Base current (DC)	I <sub>B(DC)</sub>	1.0	Α
Total power dissipation	Рт (Tc = 25°C)	30	W
Total power dissipation	PT (TA = 25°C)	2.0	W
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

**Note** PW  $\leq$  300  $\mu$ s, duty cycle  $\leq$  10%

# PACKAGE DRAWING (UNIT: mm)



1 2 3

Electrode Connection

1. Base

Collector
 Emitter

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# ELECTRICAL CHARACTERISTICS (TA = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	V <sub>CB</sub> = 60 V, I <sub>E</sub> = 0 A			10	μΑ
Emitter cutoff current	ІЕВО	V <sub>EB</sub> = 7.0 V, I <sub>C</sub> = 0 A			10	μΑ
DC current gain	h <sub>FE1</sub>	$V_{CE} = 5.0 \text{ V}, I_{C} = 1.0 \text{ A}^{Note}$	800	1,300	3,200	
DC current gain	h <sub>FE2</sub>	$V_{CE} = 5.0 \text{ V}, \text{ Ic} = 3.0 \text{ A}^{\text{Note}}$	500	1,000		
Collector saturation voltage	V <sub>CE(sat)</sub>	$I_C = 3.0 \text{ A}, I_B = 30 \text{ mA}^{\text{Note}}$		0.3	0.5	٧
Base saturation voltage	V <sub>BE(sat)</sub>	$I_C = 3.0 \text{ A}, I_B = 30 \text{ mA}^{\text{Note}}$			1.2	٧
Gain bandwidth product	f⊤	Vce = 5.0 V, Ic = 0.1 A		110		MHz
Collector capacitance	Cob	$V_{CB} = 10 \text{ V}, I_E = 0 \text{ A}, f = 1.0 \text{ MHz}$		50		pF

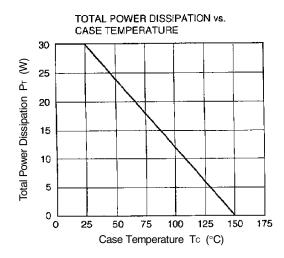
**Note** Pulse test PW  $\leq$  350  $\mu$ s, duty cycle  $\leq$  2%

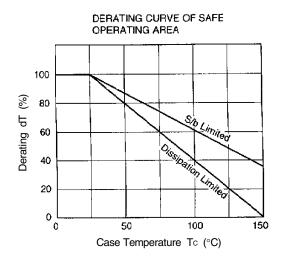
# **hfe1 CLASSIFICATION**

Marking	М	L	K
h <sub>FE1</sub>	800 to 1,600	1,000 to 2,000	1,600 to 3,200

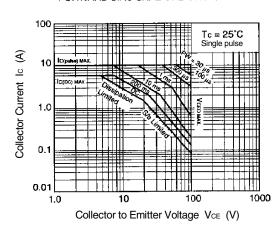


# TYPICAL CHARACTERISTICS (TA = 25°C)

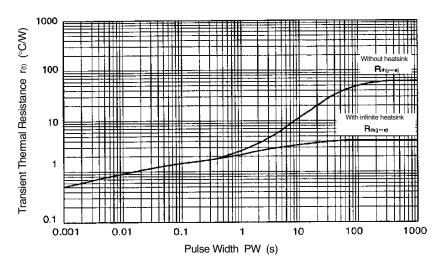




### FORWARD BIAS SAFE OPERATING AREA

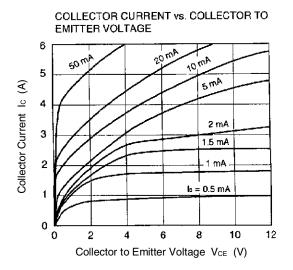


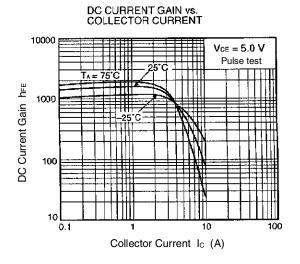
# TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

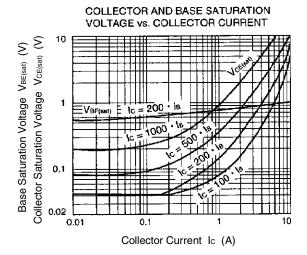


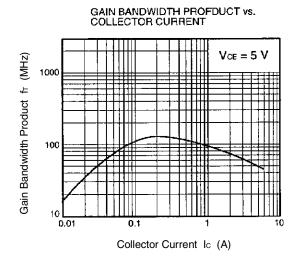
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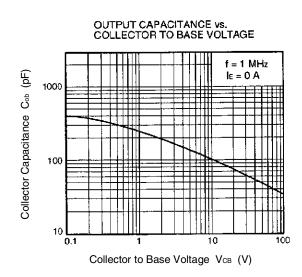
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[MEMO]

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